

### Continental Device India Limited

An ISO/TS16949 and ISO 9001 Certified Company



### NPN SILICON EPITAXIAL TRANSISTOR

2N 699

TO-39 Metal Can Package

## **General Purpose Transistor**

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	$V_{CER}$	80	V
Collector Base Voltage	$V_{CBO}$	120	V
Emitter Base Voltage	$V_{EBO}$	5	V
Total Device Dissipation @ Ta=25°C	$P_{D}$	0.6	W
Derate Above 25°C		4	mW/ºC
Total Device Dissipation@ Tc=25°C	$P_{D}$	2	W
Derate Above 25ºC		13.3	mW/ºC
Operating And Storage Junction	$T_{j},T_{stg}$	-65 to +200	°C
Temperature Range			
THERMAL RESISTANCE			
Junction to Ambient	$R_{th(j-a)}$	250	°C/W
Junction to Case	$R_{th(j-c)}$	75	°C/W

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Breakdown Voltage	BV <sub>CER</sub> *	$I_C$ =100mA, $R_{BE}$ =10 $\Omega$	80		V
Collector Cut off Current	$I_{CBO}$	$V_{CB}$ =60V, $I_{E}$ =0		2.0	μΑ
		$V_{CB}$ =60V, $I_{E}$ =0, $Ta$ =150°C	-	200	μΑ
Emitter Cut off Current	$I_{EBO}$	$V_{EB} = 2V, I_{C} = 0$		100	μΑ
DC Current Gain	h <sub>FE</sub> *	$I_C=150$ mA, $V_{CE}=10$ V	40	120	
<b>Collector Emitter Saturation Voltage</b>	V <sub>CE(Sat)</sub> *	$I_C=150$ mA, $I_B=15$ mA		5.0	V
Base Emitter Saturation Voltage	V <sub>BE(Sat)</sub> *	$I_C=150$ mA, $I_B=15$ mA		1.3	V



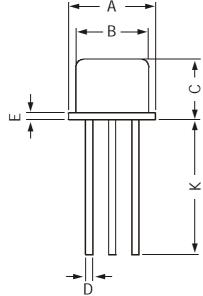
TO-39 Metal Can Package

DESCRIPTION	SYMBO	SYMBOL TEST CONDITION		MAX	UNITS
SMALL SIGNAL CHARACTERISTICS	<u> </u>				
Current Gain Bandwidth Product	$f_T$	I <sub>C</sub> =50mA,V <sub>CE</sub> =10V,f=20MHz	50		MHz
Output Capacitance	$C_obo$	$V_{CB}$ =10V, $I_{E}$ =0, f=100kHz		20	pF
Input Impedance	$h_{ib}$	$I_C=1.0$ mA, $V_{CB}=5.0$ V, $f=1.0$ kHz	20	30	$\Omega$
		$I_C$ =5.0mA, $V_{CE}$ =10V, $f$ =1.0kHz		10	$\Omega$
Voltage Feedback Ratio	$h_{rb}$	$I_C=1$ mA, $V_{CB}=5.0$ V, $f=1.0$ kHz	35	100	X10 <sup>-4</sup>
		$I_C$ =5.0mA, $V_{CB}$ =10V, $f$ =1.0kHz	45		
Small Signal Current Gain	h <sub>fe</sub>	$I_C=1.0$ mA, $V_{CB}=5.0$ V, $f=1.0$ kHz	0.05	0.5	μmho
		$I_C=5mA$ , $V_{CB}=10V$ , $f=1.0kHz$		1.0	
Output Admittance	$h_{ob}$	I <sub>C</sub> =1.0mA,V <sub>CB</sub> =5.0V,f=1.0kHz 0.05		0.5	μmho
		$I_C=5.0$ mA, $V_{CB}=10$ V, $f=1.0$ kHz		1.0	

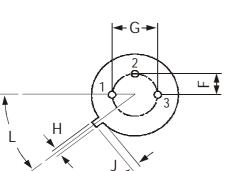
<sup>\*</sup>Pulse Test: Pulse Width ≤300µs, Duty Cycle ≤2.0%

# TO-39 Metal Can Package

## **TO-39 Metal Can Package**



DIM	MIN	MAX
Α	8.50	9.39
В	7.74	8.50
С	6.09	6.60
D	0.40	0.53
Ε	_	0.88
F	2.41	2.66
G	4.82	5.33
Н	0.71	0.86
J	0.73	1.02
Κ	12.70	_
L	42 DEG	48 DEG





All dimensions are in mm

PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

**Packing Detail** 

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

Notes 2N 699

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### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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**Data Sheet** 

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